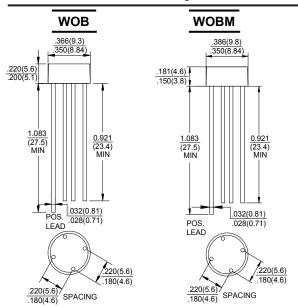
# **2WO/2WOM SERIES**

# SILICON BRIDGE RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Amperes



## **FEATURES**

- ◆ Surge overload rating -50 amperes peak
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in expensive product

#### MECHANICAL DATA

Case: Molded plastic body

Terminals: Plated leads solderable per MIL-STD-750,

Method 2026

**Polarity**: Polarity symbols marked on case

Mounting Position: Any

Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

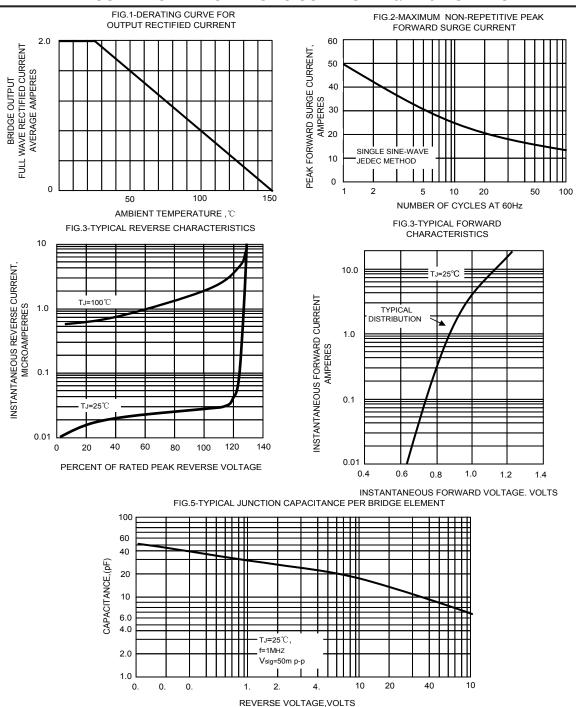
CHARACTERISTICS	SYMBOL	2W005	2W01	2W02	2W04	2W06	2W08	2W10	UNIT
		2W005M	2W01M	2W02M	2W04M	2W06M	2W08M	2W10M	
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current  0.375" (9.5mm) Lead Lengths @Ta=25 °C	I(AV)	2.0							Α
Peak Forward Surge Current , 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	IFSM	50							А
I <sup>2</sup> t Rating for Fusing (t<8.3ms)	l <sup>2</sup> t	10.375							A <sup>2</sup> s
Maximum Forward Voltage Drop Per Element at 2.0A Peak	VF	1.1							V
Maximum DC Reverse Current at Rated TJ=25℃ DC Blocking Voltage T J=100℃	lr	10.0 1.0							μA mA
Typical Junction Capacitance Per Element (Note1)	Cı	30							pF
Operating Temperature Range	TJ	-55 to +150							$^{\circ}$
Storage Temperature Range	Tstg	-55 to +150							$^{\circ}$

Note:1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2. The typical data above is for reference only.



# RATINGS AND CHARACTERISTIC CURVES 2W0/2W0M SERIES



The cruve graph is for reference only, can't be the basis for judgment

